NSN 5962-01-111-0905



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-01-111-0905 **Body Length:** 1.000 inches **Body Width:** Between 0.220 inches and 0.300 inches **Body Height:** Between 0.165 inches and 0.210 inches **Maximum Power Dissipation Rating:** 800.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs and w/enable and 3-state output **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 5.5 volts power source **Time Rating Per Chacteristic:** 40.00 nanoseconds propagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Prom **Test Data Document:** 07187-4038322 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 20 printed circuit Shelf Life: N/a **Unit Of Measure:**

Fiig: A458a0

Demilitarization: Yes - demil/mli